

L Number	Hits	Search Text	DB	Time stamp
-	43	cmos same tdi	USPAT; US-PGPUB	2003/09/09 14:48
-	315	cmos and tdi	USPAT; US-PGPUB	2003/09/11 13:01
-	174	mos and tdi	USPAT; US-PGPUB	2003/09/11 13:15
-	1385	image and tdi	USPAT; US-PGPUB	2003/09/11 13:19
-	22	aps and tdi	USPAT; US-PGPUB	2003/09/11 13:32
-	0	\$lmos and tdi	EPO; JPO	2003/09/11 13:32
-	0	(cmos or mos) and tdi	EPO; JPO	2003/09/11 13:32
-	110	(image or sensor) and tdi	EPO; JPO	2003/09/11 13:53
-	0	348/84,85,86,87,88,89,90,91,92,93,94,95.ccls. and tdi	EPO; JPO	2004/03/24 12:59
-	0	348/84,85,86,87,88,89,90,91,92,93,94,95.ccls. and line adj1 sensor	EPO; JPO	2003/09/11 13:55
-	80	tdi and (conveyer adj1 belt or assembly adj1 line)	USPAT; US-PGPUB	2003/09/15 15:38
-	0	348/295.ccls. and (conveyer adj1 belt or assembly adj1 line)	USPAT; US-PGPUB	2003/09/15 15:39
-	9	time adj1 delay adj1 integration and (conveyer adj1 belt or assembly adj1 line)	USPAT; US-PGPUB	2003/09/15 15:40
-	11	time adj1 delay adj1 integration and (conveyer or assembly adj1 line)	USPAT; US-PGPUB	2003/09/15 16:02
-	335	((348/295) or (348/302)).CCLS.	USPAT; US-PGPUB	2004/03/24 13:00
-	25	((348/295) or (348/302)).CCLS.) and @pd>20030912	USPAT; US-PGPUB	2004/03/24 13:01
-	9	poly\$crystalline adj1 silicon adj1 conductors and single adj1 layer	USPAT; US-PGPUB	2004/03/24 13:05
-	5	poly\$crystalline adj1 silicon adj1 conductors and single adj1 layer and (image adj1 sensor or cmos)	USPAT; US-PGPUB	2004/03/24 13:09
-	0	poly\$crystalline adj1 silicon adj1 conductors and single adj1 layer and (image adj1 sensor)	USPAT; US-PGPUB	2004/03/24 13:06
-	3	poly\$crystalline adj1 silicon adj1 conductors and (image adj1 sensor)	USPAT; US-PGPUB	2004/03/24 13:09
-	0	poly\$crystalline adj1 silicon adj1 conductors and (cmos same sensor)	USPAT; US-PGPUB	2004/03/24 13:09